

# n-BMS™

## **Next Generation Battery Management System**

The n-BMS is developed to meet all relevant automotive requirements. Featuring functionally safe design with key components such as Processor, ASIC and PSU carefully selected to meet functional safety at ASIL C level.

The "100809" monitoring unit (CMU) is compatible with both the n-BMS and the fully ISO26262 ASIL C certified n3-BMS, providing a convenient upgrade path for n-BMS users to a certified system.

The n-BMS can be configured with up to 32 CMU's. Each CMU can monitor up to 12 cells in series and thus the n-BMS can monitor in total up to 384 cells in series. The n-BMS can measure temperature with an accuracy up to ±1 °C.

The n-BMS uses the Creator™ software, which enables the battery designer to create a unique, application specific battery characteristics and safety strategies, while ensuring optimal peformance, charge time, and overall battery life.

#### **Highlights**

#### Safety

- · Self-test and redundancy in safety critical measurement circuits
- · Open circuit detection

#### Usability

- · RTC + logging of events, errors and warnings
- · BMS Creator PC tool for easy configuration
- · Optional current sensing (Hall effect or Shunt)
- · CAN UDS tool

#### **Battery Life**

- High frequency sampling of current (100 mS) allows optimal detection of pulses
- · Powerful and intelligent dissipative balancing at 200mA per cell
- -40° to +85°C operational range

#### **Performance**

- · ±1,6 mV at 25°C at individual cell level
- · ±1°C accuracy in temperature measurement
- · Advanced SOC algorithm with OCV compensation
- · Advanced SOH, SOP algorithm

#### **Features**

- · Safety rated key components
- · Optimized low power consumption mode
- · Various 12 and 15 voltage channel cell monitoring unit (CMU) options
- · ISO 26262 certification capable CMU

#### **Applications**

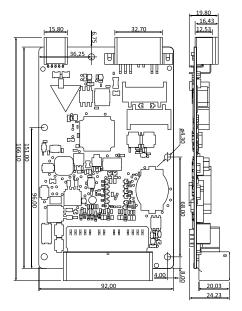








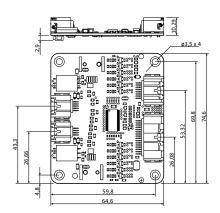
## **Next Generation Battery Management System**



n-BMS MCU

| Parameters   | Specifications   |
|--|--|
| Master Control Unit (MCU)                                  |  |
| Power supply 6-35 V  | 6-35 V   |
| Number of CMU's supported                                  | 1-32   |
| Number of cells in series for total system                 | 384  |
| Range of high voltage measurement                          | 0 - 1000 VDC   |
| Accuracy of high voltage measurement                       | ±1 VDC   |
| Range of current measurement input Shunt                   | ±150 mV  |
| Accuracy of current measurement input<br>Shunt             | ±1.0 mV -40 - 85 °C  |
| Range of current measurement input (Hall effect sensor)    | 0.0 - 5.0  V, 0.0 -2.5 V current in, $2.5  V - 5.0  V$ current out |
| Accuracy of current measurement input (Hall effect sensor) | ±1.5 mV -40 - 85 °C  |
| Accuracy of temperature (NTC)                              | ±1 °C -40 - 85 °C  |
| Ground fault detection (leakage) levels                    | 250/500/1000 $\Omega$ /V Between GND and HV+/-                     |
| Standby Consumption  | <8,5 mW at 12V supply  |
| Active Consumption   | <3,5 W at 12 V supply  |
| Communication interface, master-slave                      | isoSPI   |
| Supported CAN communication type                           | CAN 2.0A/B 11 bit and 29 bit IDs                                   |
| Supported CAN speeds                                       | 125, 250, 500, 1000 kbit/sec                                       |
| Number of CAN ports  | 2, one isolated CAN, one non-isolated CAN.                         |
| External GPIOs   | 16 (Active Low)  |
| Charger control interfaces                                 | CAN  |

### **Next Generation Battery Management System**



n-BMS CMU 100809

| Parameters                             | Specifications   |
|--|--|
| Cell Monitoring Unit (CMU)             |  |
| Number of cells per unit               | 4 - 12 Cells (minimum 12 V, to power the CMU)                      |
| Detectable cell voltage                | 0 - 5 VDC  |
| Number of temperature sensors per unit | 4 (NTC based)  |
| Cell balancing topology                | Dissipative  |
| Cell balancing current                 | 200 mA, at cell voltage 4.2 V                                      |
| Cell voltage typical sampling time     | 100 ms   |
| Accuracy of single cell voltage        | ±1,6 mV at 25 °C   |
| Range of Temperature measurements      | -40 to +85 °C  |
| Accuracy of cell temperature (NTC)     | ± 2 °C -40 - 0 °C   ± 1 °C 0 - 40 °C   ± 2 °C<br>40 - 85 °C        |
| Communication interface                | isoSPI (Max. 5 m shielded cable between boards)                    |
| Standby Consumption                    | ${\sim}460~\mu\text{W}$ (12 $\mu\text{A})$ - with 12 cells @ 3,2 V |
| Active Consumption                     | ~690 mW (18 mA) - with 12 cells @ 3,2 V                            |
| Patents                                | ZT 200780048774, EP 0781788.6, US<br>8.350.529                     |

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